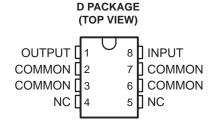
- 3-Terminal Regulators
- **Output Current up to 100 mA**
- **No External Components**
- **Internal Thermal-Overload Protection**
- **Internal Short-Circuit Current Limiting**

description/ordering information

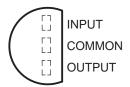
This series of fixed-voltage integrated-circuit voltage regulators is designed for a wide range of applications. These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. In addition, they can be used with power-pass elements to make high-current voltage regulators. One of these regulators can deliver up to 100 mA of output current. The internal limiting and thermal-shutdown features of these regulators essentially make them immune to overload. When used as a replacement for a Zener diode-resistor combination, an effective improvement in output impedance can be obtained, together with lower bias current.

The µA78L00C and µA78L00AC series are characterized for operation over the virtual junction temperature range of 0°C to 125°C. The µA78L05AI is characterized for operation over the virtual junction temperature range of -40°C to 125°C.

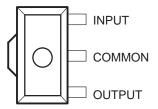


NC - No internal connection

LP PACKAGE (TO-92, TO-226AA) (TOP VIEW)









Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



description/ordering information (continued)

ORDERING INFORMATION

TJ	VO(NOM) (V)	OUTPUT VOLTAGE TOLERANCE	PACKA	GE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	261/	E0/	SOIC (D)	Tube of 75	μΑ78L02ACD	78L02A
	2.6 V	5%	TO-226/TO-92 (LP)	Bulk of 1000	μΑ78L02ACLP	78L02AC
			COIC (D)	Tube of 75	μA78L05ACD	701.05 4
			SOIC (D)	Reel of 2500	μΑ78L05ACDR	78L05A
		E9/		Bulk of 1000	μΑ78L05ACLP	
		3%	TO-226/TO-92 (LP)	Pack of 2000	μΑ78L05ACLPM	78L05AC
				Reel of 2000	μΑ78L05ACLPR	
	5% Bulk of 1000 Pack of 2000	μΑ78L05ACPK	F5			
			COIC (D)	Tube of 75	μA78L05CD	701.050
			SOIC (D)	Reel of 2500	μA78L05CDR	78L05C
		10%	TO-92 (LP)	Bulk of 1000	μΑ78L05CLP	701.050
			TO-226AA (LP)	Reel of 2000	μΑ78L05CLPR	78L05C
			SOT-89 (PK)	Tube of	μΑ78L05CPK	B5
			TO 226/TO 02 (LD)	Bulk of 1000	μΑ78L06ACLP	78L06AC
	6.2 V	5%	10-220/10-92 (LP)	Reel of 2000	μΑ78L06ACLPR	76LUGAC
			SOT-89 (PK)	Reel of 1000	μΑ78L06ACPK	F6
			SOIC (D)	Tube of 75	μΑ78L08ACD	701.004
			SOIC (D)	Reel of 2500	μΑ78L08ACDR	78L08A
0°C to 125°C		5%	TO 000/TO 00 (LP)	Bulk of 1000	μΑ78L08ACLP	701.004.0
0-0 10 125-0	8 V		10-226/10-92 (LP)	Reel of 2000	μΑ78L08ACLPR	78L08AC
		10%	SOT-89 (PK)	Reel of 1000	μΑ78L08ACPK	F8
			SOIC (D)	Tube of 75	μΑ78L08CD	701.000
				Reel of 2500	μΑ78L08CDR	78L08C
			SOIC (D)	Tube of 75	μΑ78L09ACD	78L09A
			301C (D)	Reel of 2500	μΑ78L09ACDR	76L09A
	9 V	5%	TO-226/TO-92 (LP)	Bulk of 1000	μΑ78L09ACLP	78L09AC
			10-220/10-92 (LP)	Reel of 2000	μΑ78L09ACLPR	76LU9AC
			SOT-89 (PK)	Reel of 1000	μΑ78L09ACPK	F9
			SOIC (D)	Tube of 75	μΑ78L10ACD	78L10A
			3010 (D)	Reel of 2500	μΑ78L10ACDR	/ OL TUA
	10 V	5%	TO-226/TO 02 (LD)	Bulk of 1000	μΑ78L10ACLP	78L10AC
			TO-226/TO-92 (LP)	Reel of 2000	μΑ78L10ACLPR	TOLIUAC
			SOT-89 (PK)	Reel of 1000	μΑ78L10ACPK	FA
			SOIC (D)	Tube of 75	μΑ78L12ACD	78L12A
			3010 (D)	Reel of 2500	μΑ78L12ACDR	/ OL IZA
	12 V	5%	TO 226/TO 02 (LD)	Bulk of 1000	μΑ78L12ACLP	791 1240
			TO-226/TO-92 (LP)	Reel of 2000	μΑ78L12ACLPR	78L12AC
			SOT-89 (PK)	Reel of 1000	μΑ78L12ACPK	FC

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



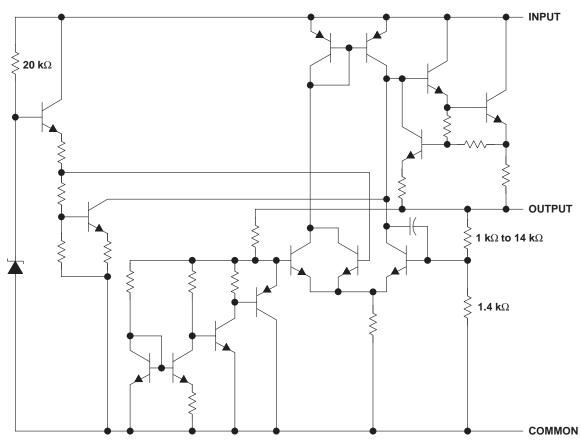
description/ordering information (continued)

ORDERING INFORMATION

TJ	V _{O(NOM)} (V)	OUTPUT VOLTAGE TOLERANCE	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
			SOIC (D)	Tube of 75	μΑ78L15ACD	78L15A
			30IC (D)	Reel of 2500	μΑ78L15ACDR	TOLISA
0°C to 125°C	15 V	5%	TO-226/TO-92 (LP)	Bulk of 1000	μΑ78L15ACLP	78L15AC
				Reel of 2000	μΑ78L15ACLPR	70LTSAC
			SOT-89 (PK)	Reel of 1000	μΑ78L15ACPK	FF
-40°C to 125°C	5 V	5%	TO-226/TO-92 (LP)	Bulk of 1000	μA78L05AILP	78L05AI
-40 C to 125 C	3 V	376	10-220/10-92 (LF)	Reel of 2000	μA78L05AILPR	70LUJAI

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

schematic



NOTE A: Resistor values shown are nominal.

absolute maximum ratings over virtual junction temperature range (unless otherwise noted)†

Input voltage, V _I : μA78L02AC, μA78L05C–μA78L09C, μA78L10AC	30 V
μΑ78L12C, μΑ78L12AC, μΑ78L15C, μΑ78L15AC	
Virtual junction temperature, T _J	150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T _{sto}	-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

package thermal data (see Note 1)

PACKAGE	PACKAGE BOARD		θ JA
SOIC (D)	High K, JESD 51-7	39°C/W	97°C/W
TO-92/TO-226AA (LP)	High K, JESD 51-7	55°C/W	140°C/W
SOT-89 (PK)	High K, JESD 51-7	9°C/W	52°C/W

NOTE 1: Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability. Due to variations in individual device electrical characteristics and thermal resistance, the built-in thermal-overload protection may be activated at power levels slightly above or below the rated dissipation.

recommended operating conditions

			MIN	MAX	UNIT	
		μΑ78L02AC	4.75	20		
		μΑ78L05C, μΑ78L05AC	7	20		
	μΑ78L06C, μΑ78L06AC	8.5	20			
l	V _I Input voltage	μΑ78L08C, μΑ78L08AC	10.5	23	V	
"		μΑ78L09C, μΑ78L09AC	11.5	24	V	
		μΑ78L10AC	12.5	25		
		μΑ78L12C, μΑ78L12AC				
		μΑ78L15C, μΑ78L15AC	17.5	30		
lo	Output current			100	mA	
Τ.	Operating virtual junction temperature range	μΑ78LxxC and μΑ78LxxAC series	0	125	°C	
TJ	Operating virtual junction temperature range	μΑ78L05AI	-40	125	<i>•</i> C	



electrical characteristics at specified virtual junction temperature, V_I = 9 V, I_O = 40 mA (unless otherwise noted)

PARAMETER	TEST CONDITIONS	-+	μ	μ Α78L02AC			
PARAMETER	TEST CONDITIONS	ΤJ [†]	MIN	TYP	MAX	UNIT	
	V 475 V (20 V	25°C	2.5	2.6	2.7		
Output voltage	$V_I = 4.75 \text{ V to } 20 \text{ V}, \qquad I_O = 1 \text{ mA to}$	0°C to 125°	C 2.45		2.75	V	
	I _O = 1 mA to 70 mA	0°C to 125°	C 2.45		2.75		
lanut valtage regulation	V _I = 4.75 V to 20 V	2500		20	100	mV	
Input voltage regulation	V _I = 5 V to 20 V	25°C	25°C 16		75	IIIV	
Ripple rejection	$V_{I} = 6 \text{ V to } 20 \text{ V}, \qquad f = 120 \text{ Hz}$	25°C	43	51		dB	
Output voltage regulation	I _O = 1 mA to 100 mA	25°C		12	50	mV	
Output voltage regulation	I _O = 1 mA to 40 mA	25 C		6	25		
Output noise voltage	f = 10 Hz to 100 kHz	25°C		30		μV	
Dropout voltage		25°C		1.7		V	
Bias current		25°C		3.6	6	mA	
Bias current		125°C			5.5	mA	
Diagram and alternative	V _I = 5 V to 20 V	0°C to 125°			2.5	mA	
Bias current change	I _O = 1 mA to 40 mA	0-0 10 125			0.1	IIIA	

[†] Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33- μ F capacitor across the input and a 0.1- μ F capacitor across the output.

electrical characteristics at specified virtual junction temperature, V_I = 10 V, I_O = 40 mA (unless otherwise noted)

PARAMETER	TEST CONDITIONS	т"‡	μ/	478L050	;		78L05A \78L05A		UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
	V. 7.V. to 20.V. In . 4 m A to 40 m A	25°C	4.6	5	5.4	4.8	5	5.2	
Output voltage	$V_{I} = 7 \text{ V to } 20 \text{ V}, \qquad I_{O} = 1 \text{ mA to } 40 \text{ mA}$	Full range	4.5		5.5	4.75		5.25	V
	I _O = 1 mA to 70 mA	Full range	4.5		5.5	4.75		5.25	
Input	V _I = 7 V to 20 V	25°C		32	200		32	150	mV
voltage regulation	V _I = 8 V to 20 V	25-0		26	150		26	100	IIIV
Ripple rejection	V _I = 8 V to 18 V, f = 120 Hz	25°C	40	49		41	49		dB
Output	I _O = 1 mA to 100 mA	25°C		15	60		15	60	mV
voltage regulation	I _O = 1 mA to 40 mA	25 C		8	30		8	30	<u>, </u>
Output noise voltage	f = 10 Hz to 100 kHz	25°C		42			42		μV
Dropout voltage		25°C		1.7			1.7		V
Bias current		25°C		3.8	6		3.8	6	mA
bias current		125°C			5.5			5.5	IIIA
Bias	V _I = 8 V to 20 V	Full range			1.5			1.5	mA
current change	$I_O = 1 \text{ mA to } 40 \text{ mA}$	Full range			0.2			0.1	IIIA

[‡] Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Full range for the μA78L05AC is T_J = 0°C to 125°C, and full range for the μA78L05AI is T_J = -40°C to 125°C.



electrical characteristics at specified virtual junction temperature, V_I = 12 V, I_O = 40 mA (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T.1	μ	478L060	;	μ Α	78L06A	С	UNIT
PARAMETER	TEST CONDITIONS	TJ [†]	MIN	TYP	MAX	MIN	TYP	MAX	UNII
	V 0.5 V 12 00 V 1 4 22 A 12 40 22 A	25°C	5.7	6.2	6.7	5.95	6.2	6.45	
Output voltage	$V_{I} = 8.5 \text{ V to } 20 \text{ V}, I_{O} = 1 \text{ mA to } 40 \text{ mA}$	0°C to 125°C	5.6		6.8	5.9		6.5	V
	I _O = 1 mA to 70 mA	0°C to 125°C	5.6		6.8	5.9		6.5	
Input	V _I = 8.5 V to 20 V	25°C		35	200		35	175	\/
voltage regulation	V _I = 9 V to 20 V	25°C		29	150		29	125	mV
Ripple rejection	V _I = 10 V to 20 V, f = 120 Hz	25°C	39	48		40	48		dB
Output	I _O = 1 mA to 100 mA	25°C		16	80		16	80	mV
voltage regulation	I _O = 1 mA to 40 mA			9	40		9	40	1111
Output noise voltage	f = 10 Hz to 100 kHz	25°C		46			46		μV
Dropout voltage		25°C		1.7			1.7		V
Diag gurrant		25°C		3.9	6		3.9	6	A
Bias current		125°C			5.5			5.5	mA
Bias	V _I = 9 V to 20 V	0°C to 125°C			1.5			1.5	mΛ
current change	I _O = 1 mA to 40 mA	0°C to 125°C			0.2			0.1	mA

[†] Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output.

electrical characteristics at specified virtual junction temperature, V_I = 14 V, I_O = 40 mA (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T.1	μ	478L080	;	μ Α	78L08A	С	UNIT
PARAMETER	TEST CONDITIONS	TJ [†]	MIN	TYP	MAX	MIN	TYP	MAX	UNII
	V. 40.5 V to 92 V . Is 4 mA to 40 mA	25°C	7.36	8	8.64	7.7	8	8.3	
Output voltage	$V_{\rm I} = 10.5 \text{ V to } 23 \text{ V}, I_{\rm O} = 1 \text{ mA to } 40 \text{ mA}$	0°C to 125°C	7.2		8.8	7.6		8.4	V
	I _O = 1 mA to 70 mA	0°C to 125°C	7.2		8.8	7.6		8.4	
Input voltage	V _I = 10.5 V to 23 V	25°C		42	200		42	175	mV
regulation	V _I = 11 V to 23 V	25 C		36	150		36	125	IIIV
Ripple rejection	V _I = 13 V to 23 V, f = 120 Hz	25°C	36	46		37	46		dB
Output voltage	I _O = 1 mA to 100 mA	25°C		18	80		18	80	mV
regulation	I _O = 1 mA to 40 mA	25 C		10	40		10	40] """
Output noise voltage	f = 10 Hz to 100 kHz	25°C		54			54		μV
Dropout voltage		25°C		1.7			1.7		V
Bias current		25°C		4	6		4	6	mA
bias current		125°C			5.5			5.5	IIIA
Bias	V _I = 11 V to 23 V	0°C to 125°C			1.5			1.5	mA
current change	I _O = 1 mA to 40 mA	0°C to 125°C			0.2			0.1	IIIA

[†] Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output.



electrical characteristics at specified virtual junction temperature, V_I = 16 V, I_O = 40 mA (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T.1	μ	478L090	;	μΑ	78L09A	С	UNIT
PARAMETER	TEST CONDITIONS	TJ [†]	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
	V. 42 V. to 24 V. I 4 m A to 40 m A	25°C	8.3	9	9.7	8.6	9	9.4	
Output voltage	$V_I = 12 \text{ V to } 24 \text{ V}, I_O = 1 \text{ mA to } 40 \text{ mA}$	0°C to 125°C	8.1		9.9	8.55		9.45	V
	I _O = 1 mA to 70 mA	0°C to 125°C	8.1		9.9	8.55		9.45	
Input	V _I = 12 V to 24 V	25°C		45	225		45	175	mV
voltage regulation	V _I = 13 V to 24 V	25°C		40	175		40	125	IIIV
Ripple rejection	V _I = 15 V to 25 V, f = 120 Hz	25°C	36	45		38	45		dB
Output	I _O = 1 mA to 100 mA	25°C		19	90		19	90	mV
voltage regulation	I _O = 1 mA to 40 mA	25 C		11	40		11	40	IIIV
Output noise voltage	f = 10 Hz to 100 kHz	25°C		58			58		μV
Dropout voltage		25°C		1.7			1.7		V
Bias current		25°C		4.1	6		4.1	6	mA
bias current		125°C			5.5			5.5	IIIA
Bias	V _I = 13 V to 24 V	0°C to 125°C			1.5			1.5	mA
current change	$I_O = 1 \text{ mA to } 40 \text{ mA}$	0 0 10 125 0			0.2			0.1	IIIA

[†] Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-µF capacitor across the input and a 0.1-µF capacitor across the output.

electrical characteristics at specified virtual junction temperature, V_I = 14 V, I_O = 40 mA (unless otherwise noted)

PARAMETER	TEST O	ONDITIONS	_ +	μ Α	78L10A	С	UNIT
PARAMETER	IESI C	ONDITIONS	T _J †	MIN	TYP	MAX	UNII
	V: 42 V/to 25 V/	1- 1 m \ to 10 m \	25°C	9.6	10	10.4	
Output voltage	$V_{\parallel} = 13 \text{ V to } 25 \text{ V},$	$I_{O} = 1 \text{ mA to } 40 \text{ mA}$	0°C to 125°C	9.5		10.5	V
	$I_O = 1 \text{ mA to } 70 \text{ mA}$		0°C to 125°C	9.5		10.5	
Input voltage regulation	V _I = 13 V to 25 V		25°C		51	175	mV
input voltage regulation	V _I = 14 V to 25 V		25 C		42	125	IIIV
Ripple rejection	$V_{I} = 15 \text{ V to } 25 \text{ V},$	f = 120 Hz	25°C	37	44		dB
Output voltage regulation	$I_O = 1 \text{ mA to } 100 \text{ mA}$	25°C		20	90	mV	
Output voltage regulation	$I_O = 1 \text{ mA to } 40 \text{ mA}$	I _O = 1 mA to 40 mA			11		40
Output noise voltage	f = 10 Hz to 100 kHz		25°C		62		μV
Dropout voltage			25°C		1.7		V
Bias current			25°C		4.2	6	mA
bias current						5.5	ША
Dies summent change	V _I = 14 V to 25 V		0°C to 125°C			1.5	mA
Bias current change	$I_O = 1 \text{ mA to } 40 \text{ mA}$		7 0 0 10 125 0			0.1	IIIA

[†] Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output.



electrical characteristics at specified virtual junction temperature, $V_{\rm I}$ = 19 V, $I_{\rm O}$ = 40 mA (unless otherwise noted)

PARAMETER	TEST CONDITIONS	t	μ	478L120	;	μ Α	78L12A	С	UNIT
PARAMETER	TEST CONDITIONS	TJ [†]	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
	V: 44 V/45 27 V	25°C	11.1	12	12.9	11.5	12	12.5	
Output voltage	$V_I = 14 \text{ V to } 27 \text{ V}, I_O = 1 \text{ mA to } 40 \text{ mA}$	0°C to 125°C	10.8		13.2	11.4		12.6	V
	I _O = 1 mA to 70 mA	0°C to 125°C	10.8		13.2	11.4		12.6	
Input	V _I = 14.5 V to 27 V	25°C		55	250		55	250	mV
voltage regulation	V _I = 16 V to 27 V	25°C		49	200		49	200	IIIV
Ripple rejection	V _I = 15 V to 25 V, f = 120 Hz	25°C	36	42		37	42		dB
Output	I _O = 1 mA to 100 mA	25°C		22	100		22	100	mV
voltage regulation	I _O = 1 mA to 40 mA	25°C		13	50		13	50	IIIV
Output noise voltage	f = 10 Hz to 100 kHz	25°C		70			70		μV
Dropout voltage		25°C		1.7			1.7		V
Diag gurrant		25°C		4.3	6.5		4.3	6.5	A
Bias current		125°C			6			6	mA
Bias	V _I = 16 V to 27 V	0°C to 125°C			1.5			1.5	mA
current change	I _O = 1 mA to 40 mA	0 0 10 1250			0.2			0.1	IIIA

[†] Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output.

electrical characteristics at specified virtual junction temperature, V_I = 23 V, I_O = 40 mA (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T _J †	μ Α78L15C			μ Α78L15AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	UNII
Output voltage	$V_{I} = 17.5 \text{ V to } 30 \text{ V}, \qquad I_{O} = 1 \text{ mA to } 40 \text{ mA}$	25°C	13.8	15	16.2	14.4	15	15.6	V
		0°C to 125°C	13.5		16.5	14.25		15.75	
	I _O = 1 mA to 70 mA	0°C to 125°C	13.5		16.5	14.25		15.75	
Input voltage regulation	V _I = 17.5 V to 30 V	25°C		65	300		65	300	mV
	V _I = 20 V to 30 V			58	250		58	250	
Ripple rejection	V _I = 18.5 V to 28.5 V, f = 120 Hz	25°C	33	39		34	39		dB
Output voltage regulation	I _O = 1 mA to 100 mA	25°C		25	150		25	150	mV
	I _O = 1 mA to 40 mA			15	75		15	75	
Output noise voltage	f = 10 Hz to 100 kHz	25°C		82			82		μV
Dropout voltage		25°C		1.7			1.7		V
Bias current		25°C		4.6	6.5		4.6	6.5	mA
		125°C			6			6	
Bias current change	V _I = 10 V to 30 V	0°C to 125°C			1.5			1.5	mA
	I _O = 1 mA to 40 mA	0°C to 125°C			0.2			0.1	111/4

[†] Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output.



APPLICATION INFORMATION

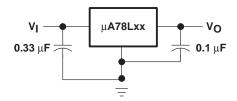


Figure 1. Fixed-Output Regulator

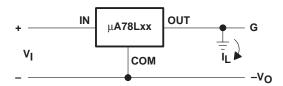


Figure 2. Positive Regulator in Negative Configuration (V_I Must Float)

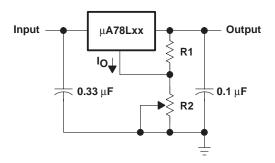


Figure 3. Adjustable-Output Regulator

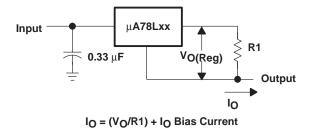


Figure 4. Current Regulator

APPLICATION INFORMATION

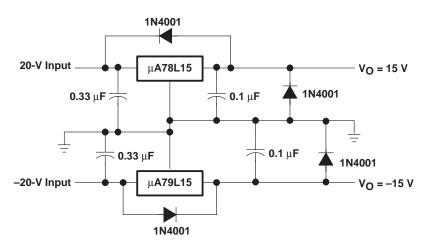


Figure 5. Regulated Dual Supply

operation with a load common to a voltage of opposite polarity

In many cases, a regulator powers a load that is not connected to ground, but instead, is connected to a voltage source of opposite polarity (e.g., operational amplifiers, level-shifting circuits, etc.). In these cases, a clamp diode should be connected to the regulator output as shown in Figure 6. This protects the regulator from output polarity reversals during startup and short-circuit operation.

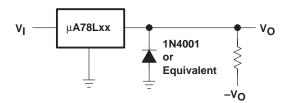


Figure 6. Output Polarity-Reversal-Protection Circuit

reverse-bias protection

Occasionally, the input voltage to the regulator can collapse faster than the output voltage. This can occur, for example, when the input supply is crowbarred during an output overvoltage condition. If the output voltage is greater than approximately 7 V, the emitter-base junction of the series-pass element (internal or external) could break down and be damaged. To prevent this, a diode shunt can be employed as shown in Figure 7.

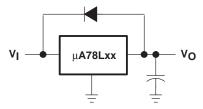
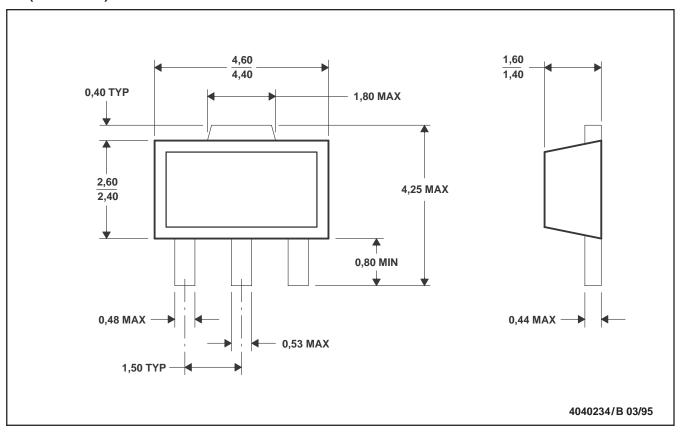


Figure 7. Reverse-Bias-Protection Circuit



PK (R-PSSO-F3)

PLASTIC SINGLE-IN-LINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

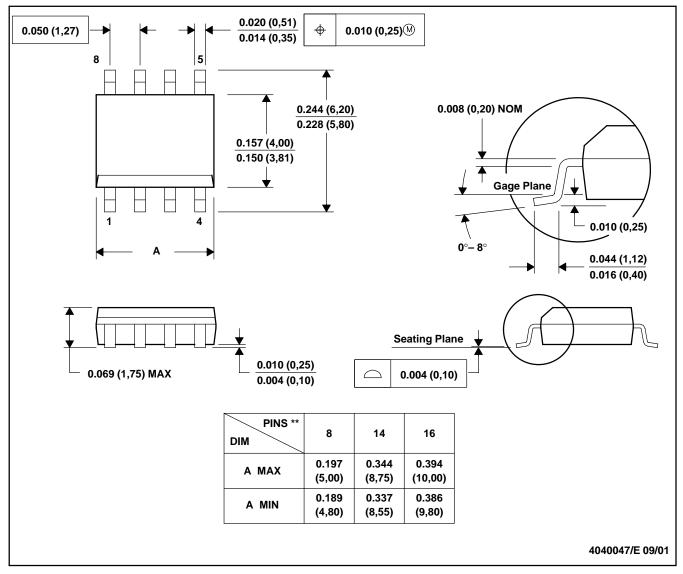
B. This drawing is subject to change without notice.

C. The center lead is in electrical contact with the tab.

D (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

8 PINS SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

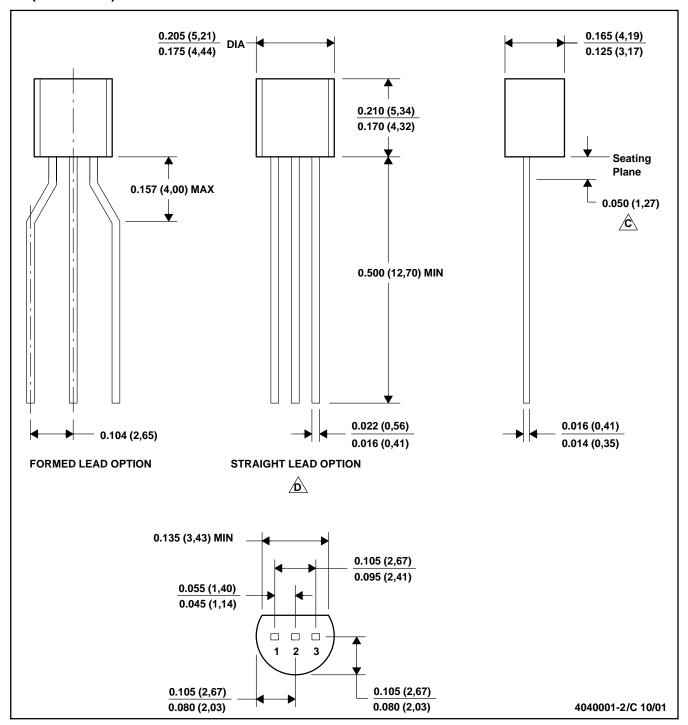
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012

LP (O-PBCY-W3)

PLASTIC CYLINDRICAL PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice. $\hfill \hfill \$

C.\ Lead dimensions are not controlled within this area

D. FAlls within JEDEC TO -226 Variation AA (TO-226 replaces TO-92)

E. Shipping Method:

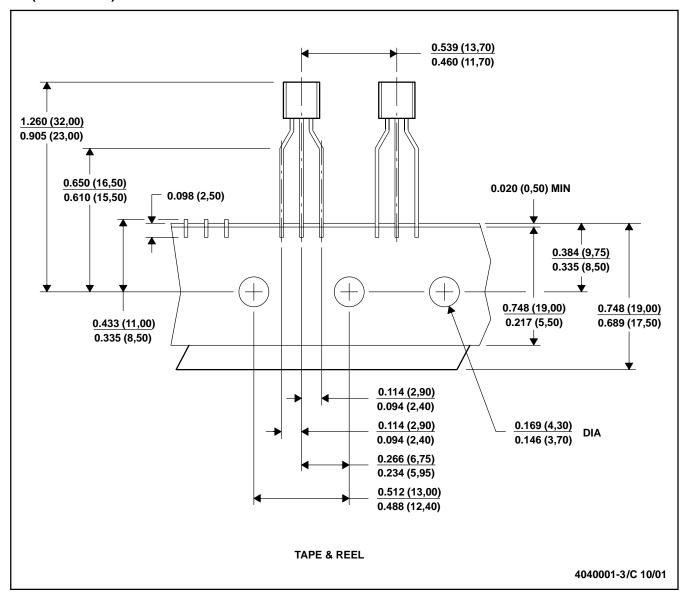
Straight lead option available in bulk pack only.

Formed lead option available in tape & reel or ammo pack.



LP (O-PBCY-W3)

PLASTIC CYLINDRICAL PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Tape and Reel information for the Format Lead Option package.

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